

## DS34C86T Quad CMOS Differential Line Receiver

Check for Samples: [DS34C86T](#)

### FEATURES

- **CMOS Design for Low Power**
- **$\pm 0.2\text{V}$  Sensitivity Over the Input Common Mode Voltage Range**
- **Typical Propagation Delays: 19 ns**
- **Typical Input Hysteresis: 60 mV**
- **Inputs Won't Load Line when  $V_{CC} = 0\text{V}$**
- **Meets the Requirements of EIA Standard RS-422**
- **TRI-STATE Outputs for System Bus Compatibility**
- **Available in Surface Mount**
- **Open Input Failsafe Feature, Output High for Open Input**

### DESCRIPTION

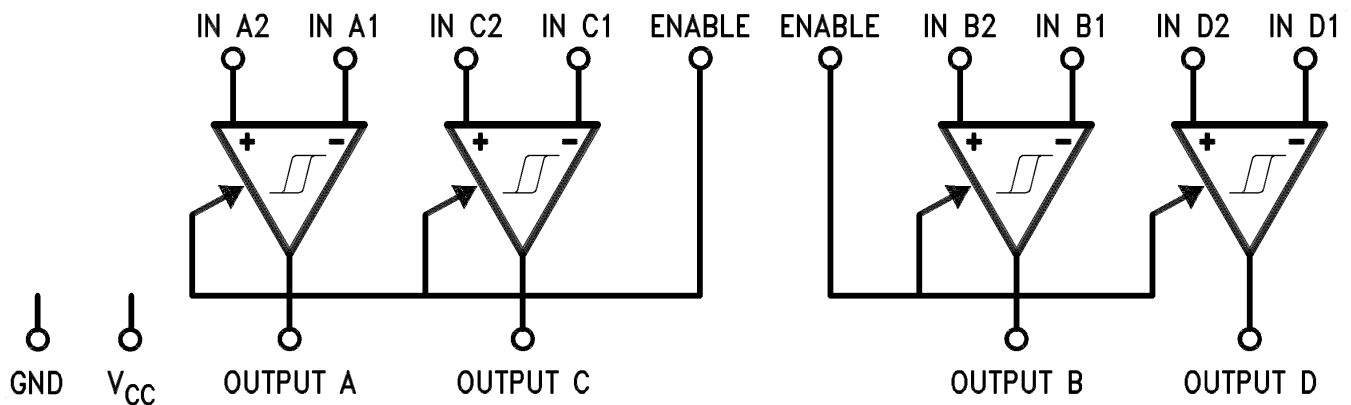
The DS34C86T is a quad differential line receiver designed to meet the RS-422, RS-423, and Federal Standards 1020 and 1030 for balanced and unbalanced digital data transmission, while retaining the low power characteristics of CMOS.

The DS34C86T has an input sensitivity of 200 mV over the common mode input voltage range of  $\pm 7\text{V}$ . Hysteresis is provided to improve noise margin and discourage output instability for slowly changing input waveforms.

The DS34C86T features internal pull-up and pull-down resistors which prevent output oscillation on unused channels.

Separate enable pins allow independent control of receiver pairs. The TRI-STATE outputs have 6 mA source and sink capability. The DS34C86T is pin compatible with the DS3486.

### Logic Diagram



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Connection Diagram

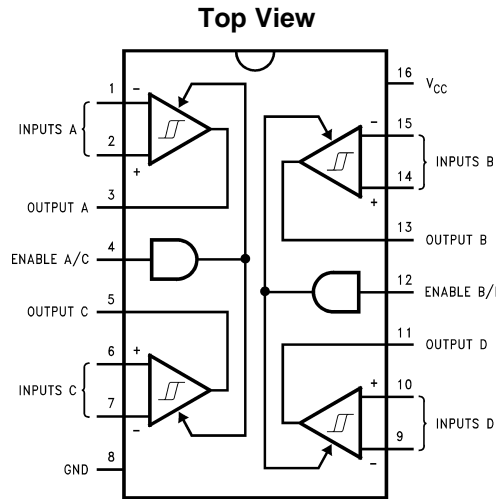


Figure 1. PDIP Package  
See Package Numbers D0016A or NFG0016E

Truth Table<sup>(1)</sup>

Enable	Input	Output
L	X	Z
H	$V_{ID} \geq V_{TH}$ (Max)	H
H	$V_{ID} \leq V_{TH}$ (Min)	L
H	Open*	H

(1) Open, not terminated. Z = TRI-STATE



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings<sup>(1)(2)(3)(4)</sup>

Supply Voltage ( $V_{CC}$ )	7V
Input Common Mode Range ( $V_{CM}$ )	$\pm 14V$
Differential Input Voltage ( $V_{DIFF}$ )	$\pm 14V$
Enable Input Voltage ( $V_{IN}$ )	7V
Storage Temperature Range ( $T_{STG}$ )	$-65^{\circ}C$ to $+150^{\circ}C$
Lead Temperature (Soldering 4 sec)	$260^{\circ}C$
Maximum Power Dissipation at $25^{\circ}C$ <sup>(5)</sup>	
PDIP Package	1645 mW
SOIC Package	1190 mW
Current Per Output	$\pm 25$ mA
This device does not meet 2000V ESD rating <sup>(1)</sup>	

- (1) ESD Rating; HBM (1.5k $\Omega$ , 100 pF) Inputs  $\geq 2000V$  All other pins  $\geq 1000V$  EIAJ (0 $\Omega$ , 200 pF)  $\geq 350V$
- (2) Unless otherwise specified, all voltages are referenced to ground.
- (3) Absolute Maximum Ratings are values beyond which the safety of the device cannot be specified. They are not meant to imply that the device should be operated at these limits. The "Electrical Characteristics" provide conditions for actual device operation.
- (4) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (5) Ratings apply to ambient temperature at  $25^{\circ}C$ . Above this temperature derate NFG0016E Package 13.16 mW/ $^{\circ}C$ , and D0016A Package 9.52 mW/ $^{\circ}C$ .

## Operating Conditions

	Min	Max	Unit
Supply Voltage ( $V_{CC}$ )	4.50	5.50	V
Operating Temperature Range ( $T_A$ )	-40	+85	°C
Enable Input Rise or Fall Times		500	ns

## DC Electrical Characteristics<sup>(1)</sup>

 $V_{CC} = 5V \pm 10\%$  (unless otherwise specified)

Parameter		Test Conditions	Min	Typ	Max	Units
$V_{TH}$	Minimum Differential Input Voltage	$V_{OUT} = V_{OH}$ or $V_{OL}$ $-7V < V_{CM} < +7V$	-200	35	+200	mV
$R_{IN}$	Input Resistance	$V_{IN} = -7V, +7V$ (Other Input = GND)	5.0	6.8	10	k $\Omega$
$I_{IN}$	Input Current (Under Test)	$V_{IN} = +10V$ , Other Input = GND		+1.1	+1.5	mA
		$V_{IN} = -10V$ , Other Input = GND		-2.0	-2.5	mA
$V_{OH}$	Minimum High Level Output Voltage	$V_{CC} = \text{Min.}$ , $V_{(DIFF)} = +1V$ $I_{OUT} = -6.0 \text{ mA}$	3.8	4.2		V
$V_{OL}$	Maximum Low Level Output Voltage	$V_{CC} = \text{Max.}$ , $V_{(DIFF)} = -1V$ $I_{OUT} = 6.0 \text{ mA}$		0.2	0.3	V
$V_{IH}$	Minimum Enable High Input Level Voltage		2.0			V
$V_{IL}$	Maximum Enable Low Input Level Voltage				0.8	V
$I_{OZ}$	Maximum TRI-STATE Output Leakage Current	$V_{OUT} = V_{CC}$ or GND, TRI-STATE Control = $V_{IL}$		$\pm 0.5$	$\pm 5.0$	$\mu\text{A}$
$I_I$	Maximum Enable Input Current	$V_{IN} = V_{CC}$ or GND			$\pm 1.0$	$\mu\text{A}$
$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$ , $V_{(DIFF)} = +1V$		16	23	mA
$V_{HYST}$	Input Hysteresis	$V_{CM} = 0V$		60		mV

(1) Unless otherwise specified, Min/Max limits apply across the operating temperature range. All typicals are given for  $V_{CC} = 5V$  and  $T_A = 25^\circ\text{C}$ .

## AC Electrical Characteristics<sup>(1)</sup>

 $V_{CC} = 5V \pm 10\%$  (unless otherwise specified) (Figure 2, Figure 3, Figure 4)

Parameter		Test Conditions	Min	Typ	Max	Units
$t_{PLH}$ , $t_{PHL}$	Propagation Delay Input to Output	$C_L = 50 \text{ pF}$ $V_{DIFF} = 2.5V$ $V_{CM} = 0V$		19	30	ns
$t_{RISE}$ , $t_{FALL}$	Output Rise and Fall Times	$C_L = 50 \text{ pF}$ $V_{DIFF} = 2.5V$ $V_{CM} = 0V$		4	9	ns
$t_{PLZ}$ , $t_{PHZ}$	Propagation Delay ENABLE to Output	$C_L = 50 \text{ pF}$ $R_L = 1000\Omega$ $V_{DIFF} = 2.5V$		13	18	ns
$t_{PZL}$ , $t_{PZH}$	Propagation Delay ENABLE to Output	$C_L = 50 \text{ pF}$ $R_L = 1000\Omega$ $V_{DIFF} = 2.5V$		13	21	ns

(1) Unless otherwise specified, Min/Max limits apply across the operating temperature range. All typicals are given for  $V_{CC} = 5V$  and  $T_A = 25^\circ\text{C}$ .

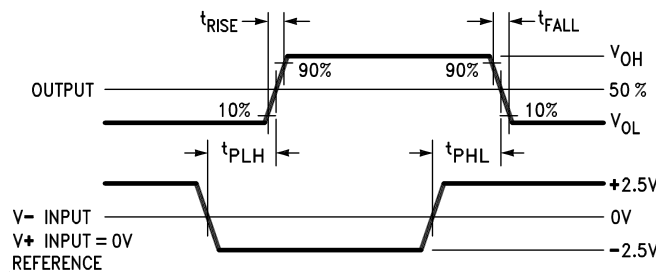
**Comparison Table of Switching Characteristics into “LS-Type” Load<sup>(1)</sup>**

$V_{CC} = 5V, T_A = 25^{\circ}C$  (Figure 5, Figure 6)

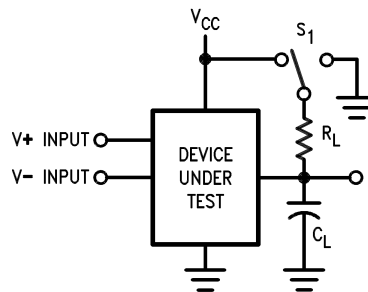
Parameter		DS34C86		DS3486		Units
		Typ	Max	Typ	Max	
$t_{PHL(D)}$	Propagation Delay Time Output High to Low	17		19		ns
$t_{PLH(D)}$	Propagation Delay Time Output Low to High	19		19		ns
$t_{PLZ}$	Output Low to TRI-STATE	13		23		ns
$t_{PHZ}$	Output High to TRI-STATE	12		25		ns
$t_{PZH}$	Output TRI-STATE to High	13		18		ns
$t_{PZL}$	Output TRI-STATE to Low	13		20		ns

(1) This table is provided for comparison purposes only. The values in this table for the DS34C86 reflect the performance of the device but are not tested or specified.

**TEST AND SWITCHING WAVEFORMS**



**Figure 2. Propagation Delays**



$C_L$  Includes load and test jig capacitance.  
 $S1 = V_{CC}$  for  $t_{PZL}$ , and  $t_{PLZ}$  measurements.  
 $S1 = GND$  for  $t_{PZH}$ , and  $t_{PHZ}$  measurements.

**Figure 3. Test Circuit for TRI-STATE Output Tests**

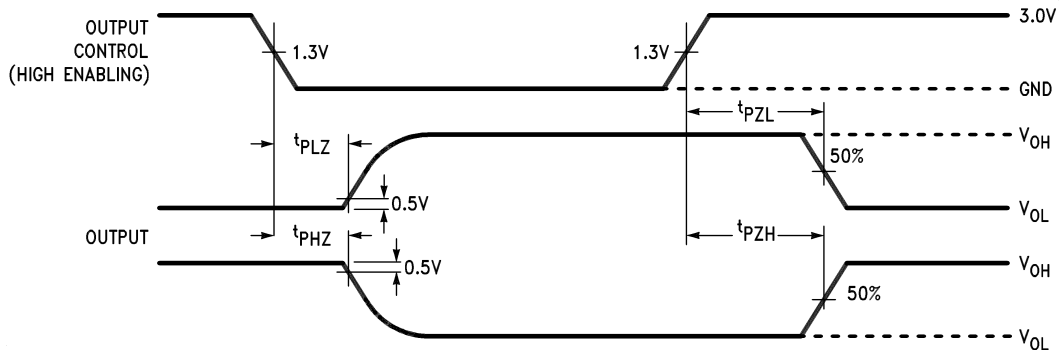
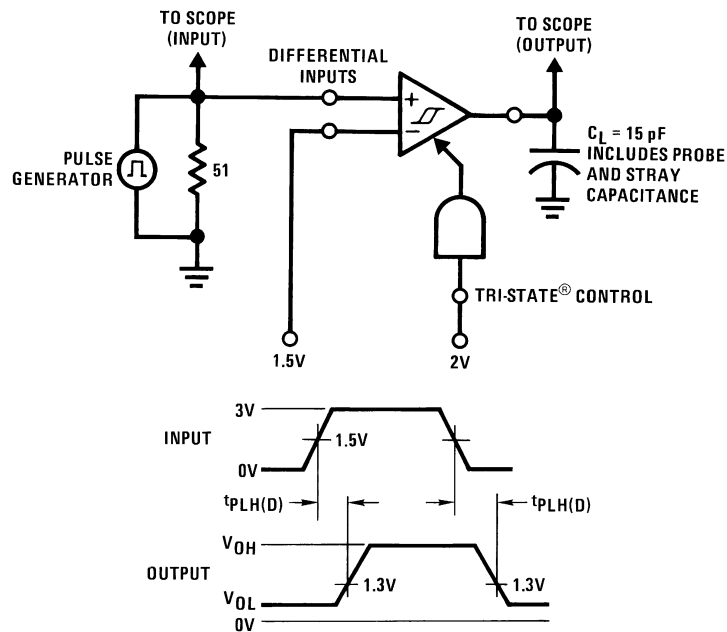


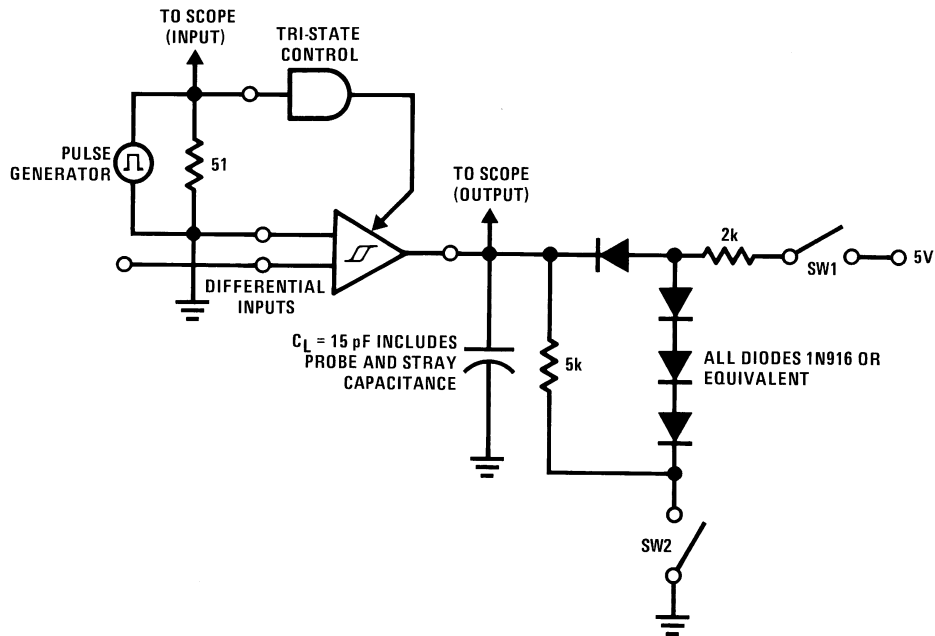
Figure 4. TRI-STATE Output Enable and Disable Waveforms

AC Test Circuits and Switching Time Waveforms



Input Pulse Characteristics:  
 $t_{TLH} = t_{THL} = 6 \text{ ns}$  (10% to 90%)  
 PRR = 1 MHz, 50% duty cycle

Figure 5. Propagation Delay Differential Input to Output for “LS-Type” Load



1.5V for  $t_{pHZ}$  and  $t_{pLZ}$   
 -1.5V for  $t_{pLZ}$  and  $t_{pZL}$   
 Input Pulse Characteristics:  
 $t_{TLH} = t_{THL} = 6$  ns (10% to 90%)  
 PRR = 1 MHz, 50% duty cycle

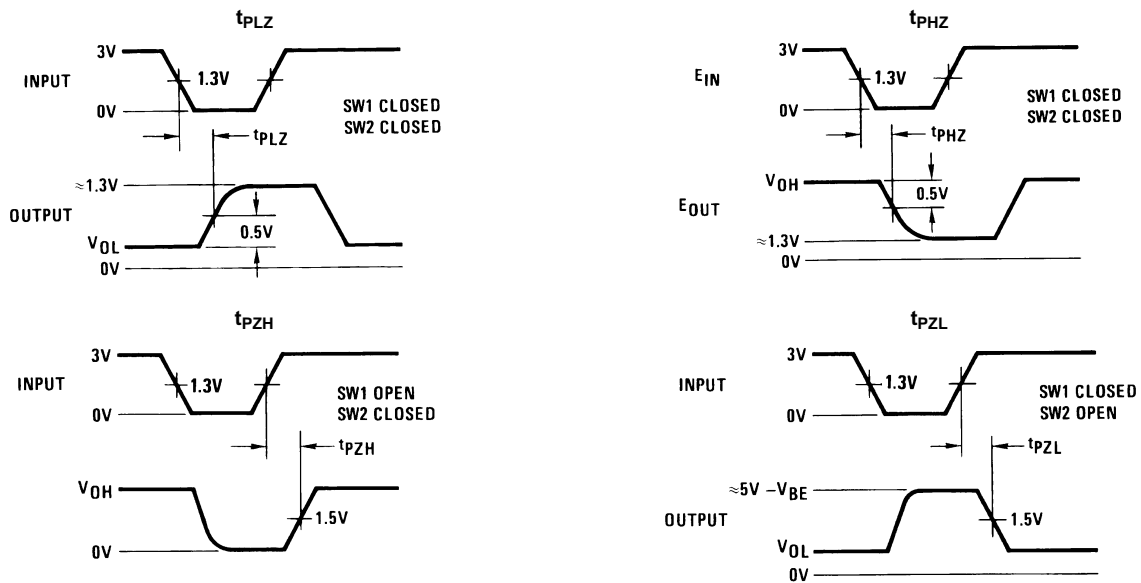


Figure 6. Propagation Delay TRI-STATE Control Unit to Output for “LS-Type” Load

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**REVISION HISTORY**

<b>Changes from Revision B (April 2013) to Revision C</b>	<b>Page</b>
<hr/> <ul style="list-style-type: none"><li>• Changed layout of National Data Sheet to TI format .....</li></ul>	<hr/> <b>6</b>

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">DS34C86TM/NOPB</a>	Active	Production	SOIC (D)   16	48   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34C86TM
DS34C86TM/NOPB.A	Active	Production	SOIC (D)   16	48   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34C86TM
<a href="#">DS34C86TMX/NOPB</a>	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34C86TM
DS34C86TMX/NOPB.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS34C86TM

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS34C86TMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS34C86TMX/NOPB	SOIC	D	16	2500	356.0	356.0	35.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
DS34C86TM/NOPB	D	SOIC	16	48	495	8	4064	3.05
DS34C86TM/NOPB.A	D	SOIC	16	48	495	8	4064	3.05

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

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Last updated 10/2025